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4. Application number(s) or patent number(s): If this document is being filed together with a new application, the execution	ution date of the application is:
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PATENT REEL: 013231 FRAME: 0010

ASSIGNMENT

do herewith assign the following patent applications and patents

- 1) US patent application 09/157,655 filed on 21 September 1998 and entitled "Pixel structure for imaging devices";
- 2) Japanese patent application 265479/1999 filed on 20 September 1999 and entitled "Pixel structure for imaging devices";
- 3) US patent 6 011 251 filed on 9 February 1998, granted on 4 January 2000 and entitled "Method for obtaining a high dynamic range read-out signal of a CMOS-based pixel structure and such CMOS-based pixel structure";
- 4) Japanese patent application 027264/1998 filed on 9 February 1998 and entitled "Method for obtaining a high dynamic range read-out signal of a CMOS-based pixel structure and such CMOS-based pixel structure";
- 5) US patent application 09/460,630 filed on 14 December 1999 and entitled "Buried, fully depletable, high fill factor photodiodes";

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- 6) US patent application 09/460,473 filed on 14 December 1999 and entitled "Method for obtaining a high dynamic range read-out signal on a pixel structure of an imaging device";
- 7) US patent 5 010 245 filed on 25 May 1989, granted on 23 April 1991 and entitled "Radiation transducing device with location identification";
- 8) European patent EP-B1-349 027 filed on 25 May 1989, granted on 2 August 1995 and entitled "Image portion determination of a solid state imaging device";
- 9) US patent 6 225 670 filed on 9 February 1998, granted on 1 May 2001 and entitled "A detector for electromagnetic radiation, pixel structure with high sensitivity using such detector and method of manufacturing such detector";
- 10) Japanese patent application 067575/1998 filed on 9 February 1998 and entitled "A detector for electromagnetic radiation, pixel structure with high sensitivity using such detector and method of manufacturing such detector";
- 11) Korean patent application 3639/98 filed on 9 February 1998 and entitled
 "A detector for electromagnetic radiation, pixel structure with high sensitivity using such detector and method of manufacturing such detector";
- 12) US patent 5 933 190 filed on 18 April 1996, granted on 3 August 1999 and entitled "Pixel structure, image sensor using such pixel structure and corresponding peripheric circuitry";

PATENT REEL: 013231 FRAME: 0011

- ⁷13) Japanese patent application 8-132508 filed on 18 April 1996 and entitled "Pixel structure, image sensor using such pixel structure and corresponding peripheric circuitry";
 - 14) European patent EP-B1-773 669 filed on 29 October 1996, granted on 12 January 2000 and entitled "Circuit, pixel, device and method for reducing fixed pattern noise in solid state imaging devices";
 - 15) US patent 5 953 060 filed on 30 September 1998, granted on 14 September 1999 and entitled "Method for reducing fixed pattern noise in solid state imaging devices";
 - 16) European patent application 98944905.3 filed on 22 September 1998, published as EP-A-940 031 and entitled "Devices and methods for improving the image quality in an image sensor";
 - 17) US patent application 09/308,032 filed on 22 September 1998 and entitled "Devices and methods for improving the image quality in an image sensor";

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For INTERUNIVERSITAIR MICRO-ELEKTRONICA CENTRUM VZW

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name: Bart Dievichx capacity: Vice President

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